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Kind regards,

Team Nexperia

BUK218-50DC

DESCRIPTION

Monolithic dual channel high side protected power switch in TOPFET2 technology assembled in a 7 pin plastic surface mount package.

APPLICATIONS

General purpose switch for driving lamps, motors, solenoids, heaters.

FEATURES

- Vertical power TrenchMOS
- Low on-state resistance
- CMOS logic compatible
- Very low quiescent current
- Overtemperature protection
- Load current limiting
- Overload and short circuit protection
- Self resetting overcurrent protection
- Overvoltage and undervoltage shutdown with hysteresis
- Off-state open circuit load detection
- Diagnostic status indication
- Voltage clamping for turn off of inductive loads
- ESD protection on all pins
- Reverse battery, overvoltage
 and transient protection

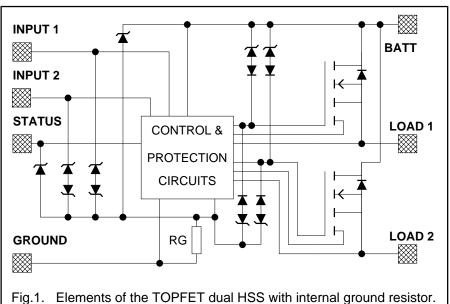
PINNING - SOT427

PIN	DESCRIPTION						
1 2 3 4 5 6 7	load 1 ground input 1 connected to mb status input 2 load 2						
mb	battery						

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MIN.	UNIT
IL.	Nominal load current (ISO)	8	A
SYMBOL	PARAMETER	MAX.	UNIT
V _{BG} IL T _j R _{ON}	Continuous off-state supply voltage Continuous load current Continuous junction temperature On-state resistance, $T_j = 25^{\circ}C$	50 16 150 40	V A °C mΩ

FUNCTIONAL BLOCK DIAGRAM

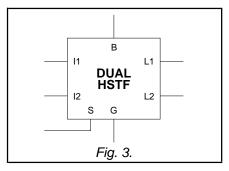


PIN CONFIGURATION

1234567

mh

SYMBOL



CONVENTION

Positive currents flow into pins, except for load and ground pins.

Fig. 2.

LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{BG}	Continuous supply voltage		0	50	V
I _L	Continuous load current per channel	T _{mb} ≤135°C	-	8	А
P _D	Total power dissipation	T _{mb} ≤25°C	-	83.3	W
T _{stg}	Storage temperature		-55	175	°C
T _j	Continuous junction temperature ¹		-40	150	°C
	Reverse battery voltages ²				
V _{GB}	Continuous reverse voltage		-	16	V
V_{GB}	Peak reverse voltage		-	32	V
	Application information				
R _I , R _s	External resistors ³	to limit input, status currents	3.2	-	kΩ
	Input and status currents				
I _I	Continuous input current		-5	5	mA
I _s	Continuous status current		-5	5	mA
I,	Repetitive peak input current	$\delta \leq 0.1$, $t_p = 300 \ \mu s$	-50	50	mA
I _S	Repetitive peak status current	$\delta \leq 0.1,t_p=300\;\mu s$	-50	50	mA
	Inductive load clamping	$V_{BG} = 13 \text{ V}, \text{ I}_{L} = 8 \text{ A}$			
E _{BL}	Non-repetitive clamping energy (one channel)	$T_j = 150^{\circ}C$ prior to turn-off	-	150	mJ

ESD LIMITING VALUE

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _c	Electrostatic discharge capacitor voltage	Human body model; C = 250 pF; R = 1.5 k Ω	-	2	kV

¹ For normal continuous operation. A higher T_j is allowed as an overload condition but at the threshold $T_{j(TO)}$ the over temperature trip operates to protect the switch.

² Reverse battery voltage is allowed only with external resistors to ensure that the input and status currents do not exceed the limiting values. The internal ground resistor limits the reverse battery ground current. The connected loads must limit the reverse load currents. Power is dissipated and the T_j rating must be observed.

³ To limit currents during reverse battery and transient overvoltages (positive or negative).

BUK218-50DC

THERMAL CHARACTERISTIC

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Thermal resistance ¹					
R_{thj-mb}	Junction to mounting base	per channel	-	2.4	3	K/W
		both channels	-	1.Z	1.5	K/W

STATIC CHARACTERISTICS

Limits are at -40 $^\circ\text{C} \leq T_{mb} \leq$ 150 $^\circ\text{C}$ and typicals at T_{mb} = 25 $^\circ\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIO	NS			MIN.	TYP.	MAX.	UNIT
	Clamping voltages								
V_{BG}	Battery to ground	$I_{G} = 1 \text{ mA}$				45	55	65	V
V _{BL}	Battery to load per channel	$I_{L} = I_{G} = 1 n$	۱A			50	55	65	V
V_{GL}	Ground to load ²	$I_{L} = 10 \text{ mA}$				18	23	28	V
		$I_{L} = 10 \text{ A}; t_{p}$	= 300 µ	ເຣ		20	25	30	V
	Supply voltage	battery to	ground						
V_{BG}	Operating range ³	-				5.5	-	35	V
	Currents	$9 V \le V_{BG} \le$	35 V						
I _B	Total quiescent current ⁴	$V_{LG} = 0 V$	$V_{LG} = 0 V$					20	μA
				T _{mb} =	= 25°C	-	0.1	1	μΑ
I _L	Off-state load current per	$V_{BL} = V_{BG}$				-	-	10	μA
	channel			T _{mb} =	= 25°C	-	0.1	1	μA
I_{G}	Operating current	one channe	el on			-	1.8	3	mA
		both chann	els on			-	3.6	6	mA
I_	Nominal load current ⁵	V _{BL} = 0.5 V	; T _{mb} = 8	85°C		8	-	-	A
R _G	Effective internal ground resistance ⁶	l _G = -200 m	A; t _p = 3	600 μs		40	75	100	Ω
	Resistances per channel	V _{BG}	I _L	t _p ⁷	Tj				
R _{on}	On-state resistance	9 to 35 V	10 A	300 µs	25°C	-	30	40	mΩ
					150°C	-	60	80	mΩ
R _{on}	On-state resistance	5.5 V	5 A	300 μs	25°C	-	50	60	mΩ
					150°C	-	100	120	mΩ

¹ Of the output Power MOS transistors.

² For a high side switch, the load pin voltage goes negative with respect to ground during the turn-off of an inductive load. This negative voltage is clamped by the device.

 $^{{\}bf 3}$ On-state resistance is increased if the supply voltage is less than 7 V.

⁴ This is the continuous current drawn from the battery when both inputs are low and includes leakage currents to the loads.

⁵ Per channel but with both channels conducting. Defined as in ISO 10483-1.

⁶ Equivalent of the parallel connected resistors for both channels.

⁷ The supply and input voltage for the R_{ON} tests are continuous. The specified pulse duration t_p refers only to the applied load current.

INPUT CHARACTERISTICS

5.5 V \leq V_{BG} \leq 35 V. Limits are at -40°C \leq T_{mb} \leq 150°C and typicals at T_{mb} = 25°C unless otherwise stated.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I,	Input current	$V_{IG} = 5 V$	20	60	160	μA
V _{IG}	Input clamping voltage	I ₁ = 200 μA	5.5	7	8.5	V
V _{IG(ON)}	Input turn-on threshold voltage		-	2.1	3	V
V _{IG(OFF)}	Input turn-off threshold voltage		1.2	1.8	-	V
ΔV_{IG}	Input turn-on hysteresis		0.15	0.3	0.5	V
I _{I(ON)}	Input turn-on current	$V_{IG} = 3 V$	-	-	100	μA
I _{I(OFF)}	Input turn-off current	V _{IG} = 1.2 V	12	-	-	μA

OPEN CIRCUIT DETECTION CHARACTERISTICS

An open circuit load on either channel can be detected in the off-state. Refer to TRUTH TABLE. This feature requires external load pull-up to a positive supply voltage via a suitable resistor. Limits are at -40°C $\leq T_{mb} \leq 150$ °C and typical is at $T_{mb} = 25$ °C.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Open circuit detection					
$V_{\text{LG(OC)}}$	Load ground threshold voltage	$V_{BG} \ge 9 V$	1.5	2.5	3.5	V
I _{B(OC)}	Supply quiescent current per OC channel	$V_{BG} = V_{LG} = 16 V$ open circuit detected, other channel off	-	0.8	1.5	mA
-I _{L(OC)}	Load ground current per channel	V _{LG} = 16 V V _{LG} = 3.5 V	-	200 22	300 40	μΑ μΑ
t _{d(OC)}	Status delay time	input low to status low	-	65	100	μs
R _{ext}	Application information External load pull-up resistance per channel	$V_{ext} = 5 V$	-	10	-	kΩ

UNDERVOLTAGE & OVERVOLTAGE CHARACTERISTICS

Limits are at -40 $^\circ\text{C} \leq T_{mb} \leq$ 150 $^\circ\text{C}$ and typicals at T_{mb} = 25 $^\circ\text{C}$. Refer to TRUTH TABLE.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Undervoltage					
V _{BG(UV)}	Low supply threshold voltage ¹		2	4.2	5.3	V
$\Delta V_{\text{BG(UV)}}$	Hysteresis		0.1	0.5	1	V
	Overvoltage					
V _{BG(OV)}	High supply threshold voltage ²		35	40	45	V
$\Delta V_{\rm BG(OV)}$	Hysteresis		0.4	1	2	V
I _{BG(OV)}	Operating current per channel	$V_{BG} > V_{BG(OV)}$	-	1	2	mA

OVERLOAD PROTECTION CHARACTERISTICS

Independent protection per channel. Refer to TRUTH TABLE. 5.5 V $\leq V_{BG} \leq 35$ V, limits are at -40°C $\leq T_{mb} \leq 150$ °C and typicals at T_{mb} = 25°C unless otherwise stated.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Overload protection	$V_{BL} = V_{BG}; t_p = 300 \ \mu s$				
I _{L(lim)}	Load current limiting	$V_{BG} \ge 8 V$	18	30	42	А
		V _{BG} = 5.5 V	15	27	42	А
	Short circuit load protection	$T_{mb} \le 125^{\circ}C$ prior to overload ³				
P _{D(TO)}	Overload power threshold	for protection ⁴	100	150	200	W
T _{DSC}	Characteristic time	which determines trip time ⁵	-	200	500	μs
	Overtemperature protection					
T _{j(TO)}	Threshold junction temperature		150	170	190	°C
$\Delta T_{j(TO)}$	Hysteresis ⁶		3	10	20	°C

¹ Undervoltage sensors causes each channel to switch off and reset.

² Overvoltage sensors causes each output channel to switch off to protect its load.

³ Above this temperature measurement of these parameters is prevented because OT protection may occur prior to SC protection.

⁴ Normal operation will be resumed when $P_D < P_{D(TO)}$ and $T_j < T_{j(TO)}$.

⁵ Trip time $t_{d \, sc}$ varies with overload dissipation P_D according to the exponential model formula $t_{d \, sc} \approx T_{DSC} / LN[P_D / P_{D(TO)}]$.

⁶ After cooling below the reset temperature the channel will resume normal operation.

STATUS CHARACTERISTICS

The status output is an open drain transistor, and requires an external pull-up circuit to indicate a logic high. Limits are at -40°C $\leq T_{mb} \leq 150$ °C and typicals at $T_{mb} = 25$ °C unless otherwise stated. Refer to TRUTH TABLE.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{SG}	Status clamping voltage	I _s = 100 μA	5.5	7	8.5	V
V _{SG(LO)}	Status low voltage	$I_{s} = 100 \mu A$	-	0.7	0.9	V
		I _s = 250 μA	-	-	1.1	V
I _s	Status leakage current	$V_{SG} = 5 V$	-	-	10	μA
		$T_{mb} = 25^{\circ}C$	-	0.1	1	μA
I _{S(SAT)}	Status saturation current ¹	V _{SG} = 5 V	5	10	15	mA
	Application information					
R _s	External pull-up resistor		-	47	-	kΩ

TRUTH TABLE

INF	νUT		ABN	-	AL C		-	ONS		LO OUT	AD PUT	STATUS	DESCRIPTION
		SUP	PLY	L	OAD	1	L	OAD	2				
1	2	UV	ov	00	SC	ОТ	00	SC	ОТ	1	2		
L	L	0	Х	0	Х	Х	0	Х	Х	OFF	OFF	Н	both off & normal
L	L	0	Х	1	Х	Х	Х	X	Х	OFF	OFF	L	both off, one/both OC or short to V+
L	Н	0	Х	1	Х	Х	0	0	0	OFF	ON	L	one off & OC, other on & normal
н	L	0	0	0	0	0	0	0	0	ON	OFF	Н	one on & normal, other off & normal
н	н	0	0	0	0	0	0	0	0	ON	ON	Н	both on & normal
н	Х	1	0	Х	Х	Х	0	X	Х	OFF	OFF	Н	supply undervoltage lockout
н	Х	0	1	Х	0	0	Х	0	0	OFF	OFF	Н	supply overvoltage shutdown
н	Х	0	0	0	1	Х	Х	Х	Х	OFF	Х	L	one SC shutdown
н	L	0	0	0	1	Х	0	0	Х	OFF	OFF	L	one SC shutdown, other off & normal
н	н	0	0	0	1	Х	0	0	0	OFF	ON	L	one SC shutdown, other on & normal
н	Х	0	0	0	0	1	Х	Х	Х	OFF	Х	L	one OT shutdown
н	L	0	0	0	0	1	0	0	Х	OFF	OFF	L	one OT shutdown, other off & normal
н	Н	0	0	0	0	1	0	0	0	OFF	ON	L	one OT shutdown, other on & normal

KEY TO ABBREVIATIONS

- logic low L
- Н logic high
- don't care Х
- condition not present condition present 0
- 1
- UV undervoltage OV overvoltage OC open circuit
- short circuit SC
- OT overtemperature

¹ For example with the pull-up resistor short circuited while the status transistor is conducting. This condition should be avoided in order to prevent possible interference with normal operation of the device.

SWITCHING CHARACTERISTICS

 T_{mb} = 25 °C, V_{BG} = 13 V, for resistive load R_{L} = 13 Ω per channel.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
	During turn-on	from input going high				
t _{d on} Delay time		to 10% V _L	-	30	-	μs
dV/dt _{on}	Rate of rise of load voltage	30% to 70% $V_{\rm L}$	0.5	1	2	V/µs
t _{on}	Total switching time	to 90% V_L	-	100	400	μs
	During turn-off	from input going low				
t _{d off}	Delay time	to 90% V _L	-	20	-	μs
dV/dt _{off}	Rate of fall of load voltage	70% to 30% V_{L}	0.5	1	2	V/µs
t _{off}	Total switching time	to 10% V_L	-	40	200	μs

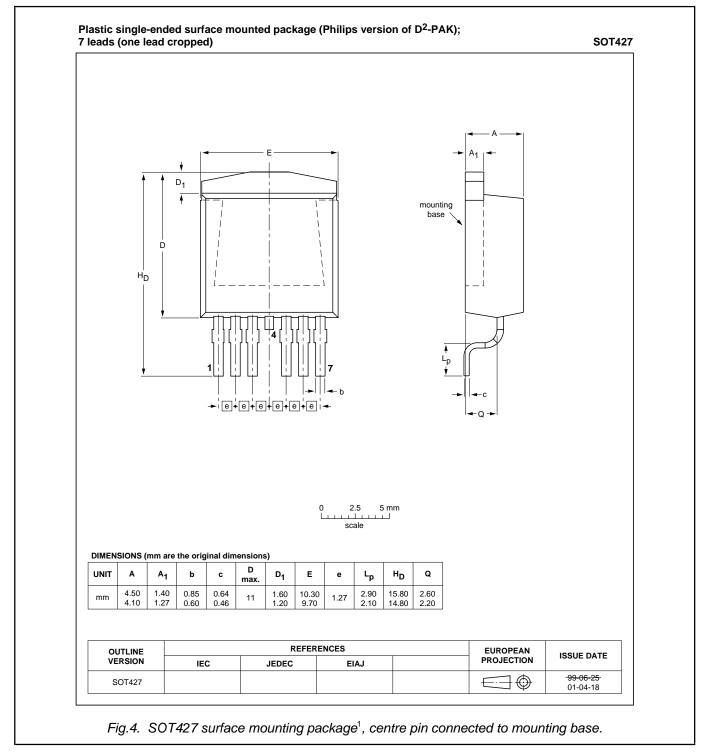
CAPACITANCES

 $T_{mb} = 25 \degree C$; f = 1 MHz; $V_{IG} = 0 V$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
C _{sg}	Status capacitance	$V_{SG} = 5 V$	-	11	15	pF
	per channel					
C _{ig}	Input capacitance	V _{BG} = 13 V	-	15	20	pF
C _{bl}	Output capacitance	V _{BL} = 13 V	-	265	375	pF

BUK218-50DC

MECHANICAL DATA



¹ Epoxy meets UL94 V0 at 1/8". Net mass: 1.5 g. For soldering guidelines and SMD footprint design, please refer to Data Handbook SC18.

BUK218-50DC

DEFINITIONS

DATA SHEET STATUS				
DATA SHEET STATUS ¹	PRODUCT STATUS ²	DEFINITIONS		
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice		
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product		
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Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

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